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Effect of High Si content on U₃Si₂ Fuel Microstructure

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ABSTRACT

The development of U₃Si₂ as an accident tolerant nuclear fuel has gained research interest due to its promising high uranium density and improved thermal properties. In the present study, three samples of U₃Si₂ fuel with varying silicon content have been fabricated by a conventional powder metallurgical route. Microstructural characterization via scanning and transmission electron microscopy reveals the presence of other stoichiometry of uranium silicide such as USi and UO₂ in both samples. The detailed phase analysis by x-ray diffraction shows the presence of secondary phases, such as USi, U₃Si, and UO₂. The samples with higher concentrations of silicon content of 7.5 wt.% displays additional elemental Si. These samples also possess an increased amount of the USi phase as compared to that in the conventional sample with 7.3 wt.% silicon. The optimization of U₃Si₂ fuel performance through the understanding of the role of Si content on its microstructure has been discussed.

INTRODUCTION

After the March 2011 events at the Fukushima Daiichi nuclear plant in Japan, improving the accident tolerance, safety, and reliability of nuclear fuel has become a topic of research interest [1]. The Department of Energy’s Fuel Cycle Research & Development Program (FCRD) is exploring new accident tolerant fuel (ATF) concepts along with industry partners, national laboratories and research universities. A more highly uranium dense fuel like U₃Si₂ will allow the same number of fissile U²³⁵ atoms to be accommodated in a smaller volume of material. This property can lead to large savings in both enrichment and fuel manufacturing costs, which are crucial aspects to evaluate in the selection of an accident-tolerant fuel [2]. U₃Si₂ (12.2 g/cm³)[3] is among the highest density fuels when compared to UAI₂ (8.1 g/cm³) [4], U₃O₉ (8.3 g/cm³) [4], UO₂ (10.97 g/cm³) [4], and USi (11.0 g/cm³) [4]. The comparatively improved thermal conductivity of U₃Si₂ can decrease the thermal gradients and generate lower centerline temperatures during fuel performance. Studies have demonstrated that from 400-1,000°C, the thermal conductivity of U₃Si₂ drastically exceeds that of UO₂ [5]. Also, from a safety perspective, improvements in thermal conductivity can potentially slow down the rise rate of the core temperature during accident conditions. Additionally, the U₃Si₂ irradiation stability of the fuel is promising, with fission gases forming small uniform bubbles with minimal coalescence, which limits fuel swelling and ultimately offers greater stability during high burnups [6]. The methods to produce U₃Si₂ fuel are high-energy ball milling (HEBM) [7], centrifugal atomization [8] and powder metallurgy [3] processes. The scope of this research work is to understand the effect of the silicon content on the microstructure of U₃Si₂ fuel fabricated by means of a conventional powder metallurgical process.

EXPERIMENTAL

Silicide fuel (U₃Si₂) was fabricated using a powder metallurgical method. The process has proved to produce densities above 95% theoretical density along with an optimized high phase purity U₃Si₂. As part of the goal to develop an industrially scalable process to produce U₃Si₂ pellets, a laboratory scale development was performed. Due to the highly pyrophoric behavior of the powders and an effort to avoid oxidation, the fabrication process took place in a glove box with an argon atmosphere with oxygen content below 10 ppm. The samples were manufactured following the procedures developed at Idaho National Laboratory [3].
One sample (C) was prepared with uranium and silicon powders in stoichiometric proportions. (92.7 wt.% and 7.3 wt.% respectively) Two additional samples (A2 and D4) were fabricated with higher amounts of silicon (U and Si powders at 92.5 wt% and 7.5 wt%, respectively) to account for the silicon loss expected during the arc melting stage. Furthermore, studies suggest the inclusion of extra silicon aids in minimizing the formation of metallic uranium and U₃Si which compromise the most U-rich phases in the U-Si system [9]. Table I displays some of the manufacturing parameters employed during the production of the U₃Si₂ samples.

The production of silicide fuels generally results in relative amounts of the various phases or distinguishable crystalline entities present in the U-Si alloy at different Si concentrations. According to previous studies, it may be essentially impossible to produce an alloy at the exact stoichiometry of the compound and of such atomistic homogeneity that only a pure phase is present [9]. A minor, but finite, amount of the phase to the left or the right on the phase diagram [10] of the compound of interest can be found in the microstructure. Furthermore, to increase the challenge of producing a pure phase, the presence of impurities, which are inevitable, can allow the formation of other phases that may or may not be noticeable under microscopy, depending on the size and the magnification employed. The impurities found can be expected to appear in a solid state, sometimes within the crystalline lattices, in each of the phases present. The aim of this work is to further explore the presence of these different phases and/or impurities using various characterization techniques with a range of resolutions.

<table>
<thead>
<tr>
<th>Sample</th>
<th>Wt.% Silicon</th>
<th>Peak Sintering Temperature (°C)</th>
<th>Sintering Atmosphere</th>
<th>Measured Density (g/cm³)</th>
</tr>
</thead>
<tbody>
<tr>
<td>A2</td>
<td>7.5</td>
<td>1,550</td>
<td>Argon</td>
<td>11.54 +/- 0.06*</td>
</tr>
<tr>
<td>D4</td>
<td>7.5</td>
<td>1,550</td>
<td>Argon</td>
<td>11.36 +/- 0.02</td>
</tr>
<tr>
<td>C</td>
<td>7.3</td>
<td>1,550</td>
<td>Vacuum</td>
<td>11.8 **</td>
</tr>
</tbody>
</table>

* Based on batch average.
** Based on batch average reported in [3].

**RESULTS AND DISCUSSION**

The samples’ morphologies, microstructures, and chemical analyses were examined using a JEOL scanning electron microscope (model JSM-6610-LV) coupled with energy dispersive x-ray spectroscopy (EDS). X-ray diffraction spectroscopy (XRD) was performed using a Rigaku Smartlab x-ray diffractometer. The transmission electron microscopy (TEM) samples were prepared by a dual-beam Quanta 3D focused ion beam instrument. Scanning transmission electron microscopy (STEM) and conventional TEM analyses were conducted on an FEI Tecnai F30 microscope operated at 300 kV. STEM images were obtained using a camera focal length of 80 mm. Chemical analyses on TEM samples were carried out using the EDAX™ energy dispersive spectroscopy (EDS) system. Gatan Digital micrograph and TIA™ (TEM imaging and analysis) software were used for post-processing of TEM data. The simulations of diffraction patterns were carried out using JEMS™ software.

Scanning electron microscopy was performed to evaluate the microstructural details in all three U₃Si₂ samples. Figure 1 shows backscattered SEM images of conventional (C) and high silicon (A2 and D4) samples. Mass contrast imaging along with chemical analysis allowed identification of the U₃Si₂ matrix, porosities, and secondary phases in all three U₃Si₂ samples. The predominant secondary phases found in the samples were USi and UO₂. As the EDS analysis on SEM is semi-quantitative, the phase identification was confirmed by using TEM-EDS and TEM- selected area diffraction (SAD). Sample A2 displays an acicular morphology of USi as displayed in Figure 1a. Samples D4 and C displayed a flakey morphology of USi as observed from SEM images on Figure 1b and Figure 1c, respectively. Higher proportions of porosity were found on sample D4 as displayed by Figure 1b and confirmed later by digital image analysis (Table II).
Digital image analysis was further employed to quantify the phase proportions of all samples (Table II). Employing a SEM backscatter electron detector along with the guidelines specified on the ASTM E-1245 [11], the area fractions of the uranium dioxide and uranium silicon-rich phases were estimated using a total of 60 SEM micrographs. These results also indicate that higher concentrations of silicon allow the formation of secondary phases of the U-Si system, predominantly USi. Although no significant statistical differences in porosity between samples with high and low silicon content were measured, there is an indication that the porosity levels between the two high silicon samples are different. At this point no reason for this could be determined from the available fabrication parameters. It was determined that the $U_3Si_2$ matrix proportion was above 80% for all three samples. Larger proportions of the secondary phase (USi) were found on samples, A2 and D4, which have higher silicon content due to silicon interaction with uranium metal during fabrication. Based on the U-Si phase diagram [10] it is suggested that the higher concentrations of silicon react, forming a USi phase during sintering at 1,550 °C. The phase quantification results are in close agreement with the work performed in [3].

The XRD analyses on the $U_3Si_2$ samples confirmed the presence of secondary phases. Three different areas were evaluated on each sample, however, for comparison purposes only, a representative pattern is displayed for each concentration of Si (7.3 and 7.5 wt.%) in Figure 2. The reference files are from 01-081-2241($U_3Si_2$), 00-041-0845 (U3Si), 00-027-0928 (USi), 00-041-1422 (UO2), and 00-005-0565 (Si). According to the XRD analyses, the secondary phases found in the samples were $U_3Si$, USi, and UO2, which are in agreement with the phases found in the electron microscopy of the present work. These findings have also been reported elsewhere [10,12]. On the samples with higher silicon content, peaks displayed the presence of silicon in its elemental state, showing incomplete reactions. The presence of $U_3Si$ is detrimental during fuel performance as it is prone to excessive swelling when compared with $U_3Si_2$ which has shown a stable swelling behavior [13]. Studies have shown that at fission densities of approximately $2.78 \times 10^{21}$ cm$^3$ $U_3Si_2$ displays a swelling rate ($\Delta V/f$) of 9.65 % and $U_3Si$ presents an increased swelling rate of 22.16% [14]. In addition, the presence of UO2 can negatively affect the thermal properties of the fuel. At temperature gradients around 1,000 °C, the thermal conductivity of UO2 tends to decrease as opposed to that of $U_3Si_2$ which increases with the temperature gradient [5]. While evaluating the presence of UO2, O2 uptake during XRD measurements was discarded; distinct UO2 phases were observed during SEM and TEM analyses showing the UO2 phase to be integral to the system and not solely to the surface of the sample.

![Fig. 1. Back scatter SEM images of $U_3Si_2$ samples. (a) Sample A2 with 7.5 wt.% Si and 0.4 % porosity. (b) Sample D4 with 7.5 wt.% Si and 1.04 % porosity. (c) Sample C with 7.3 wt.% Si and 0.64% porosity.](image)

<table>
<thead>
<tr>
<th>Sample</th>
<th>Silicon Content (wt. %)</th>
<th>Porosity (%)</th>
<th>USi (%)</th>
<th>UO2 (%)</th>
<th>$U_3Si_2$ Matrix (%)</th>
</tr>
</thead>
<tbody>
<tr>
<td>A</td>
<td>7.5</td>
<td>0.59 ± 0.28</td>
<td>13.35 ± 4.39</td>
<td>4.20 ± 0.88</td>
<td>81.86 ± 4.89</td>
</tr>
<tr>
<td>D</td>
<td>7.5</td>
<td>1.17 ± 0.24</td>
<td>9.85 ± 1.87</td>
<td>7.98 ± 1.38</td>
<td>81 ± 2.55</td>
</tr>
<tr>
<td>C</td>
<td>7.3</td>
<td>0.80 ± 0.47</td>
<td>7.65 ± 2.92</td>
<td>5.57 ± 0.70</td>
<td>85.98 ± 2.81</td>
</tr>
</tbody>
</table>
Fig. 2. XRD analysis of Samples A2 and C.

TEM

The structural identification of various phases formed within U₃Si₂ matrix has been carried out by TEM SAD. The STEM image of the conventional sample C in Figure 3a shows a grain possessing weaker mass contrast compared with that of the rest of the FIB lamellae. The SAD corresponding to the matrix is shown in Figure 3b. The SAD pattern confirms the tetragonal structure of the U₃Si₂ phase (Space group P4/mmbm). The high amount of oxygen in the darker grain compared with other parts of the lamellae, as revealed by EDS, attributes weaker mass contrast to the grain. The structure of this grain was identified as cubic UO₂ structure (Space group Fm₃m) based on the SAD pattern shown in Figure 3c. The high resolution (HR)TEM image along the [001] zone axis in Figure 3d shows the atomic structure of UO₂.

Figure 4a shows a STEM image of the high-silicon sample A2. The morphology of the grain with weaker mass contrast has been shown by a bright field image in the inset. The matrix was confirmed to be tetragonal U₃Si₂ phase from the SAD pattern as shown in Figure 4b. Although the SAD in Figure 4c confirmed the same tetragonal structure of the grain, the EDS results confirm that the weaker mass contrast of the grain is attributed from high silicon content when compared with that of the matrix. Hence, the grain was identified as USi based upon the chemical and structural analyses. Figure 4d shows the HRTEM image of the USi grain along the [211] zone axis. On sample A2, the high concentration of silicon allowed the formation of the USi compound, which is in agreement with the phase diagram [10] and the XRD results. The fuel matrix was confirmed to be U₃Si₂ by both XRD and SAD. The phases found in this analysis are in agreement with the TEM results reported in [15]. In the TEM and SAD examinations, not all the secondary phases were found due to the small volume of the TEM specimen. Future work will include additional analyses on interfaces of phases found in U₃Si₂, to confirm identity of the U₃Si phases identified by the XRD analysis.
Fig. 3. (a) STEM image of sample C (7.3 wt % Si). (b) SAD pattern of the matrix. (c) SAD pattern on grain displayed on Figure 5a. (d) HRTEM image of the UO$_2$ grain.

Fig. 4. (a) STEM image of sample A2 (7.5 wt % Si). (b) SAD on the matrix of sample A2 displaying a tetragonal crystal structure. (c) SAD on grain displayed on Figure 6a. (d) HRTEM image of the USi grain.
CONCLUSION

Two U₃Si₂ samples were prepared using a conventional fabrication process, with a higher silicon content (7.5 wt %) to account for the element loss during arc-melting, while a third sample was prepared with a silicon content of 7.3 wt%. Both concentrations of silicon allowed the formation of secondary phases, including USi, U₃Si, UO₂, and silicon in its elemental state (since it was left unreacted). The aforementioned phases were confirmed by XRD and electron microscopy. The higher-silicon samples displayed higher concentrations of USi, which were confirmed by the digital image analysis and later validated by higher intensity peaks on the XRD patterns. It is confirmed that the higher silicon content tends to react with uranium metal and form USi and U₃Si during sintering, which are the two phases surrounding U₃Si₂ in the U-Si phase diagram. The formation of UO₂ was attributed to the presence of oxygen most probably while manufacturing the uranium and silicon powders. Prevention of oxygen exposure to uranium metal and silicon is highly suggested in order to minimize the formation of the UO₂ compound. Research efforts are being made to manufacture a pure U₃Si₂ phase leading to reduced fuel swelling, which brings stability in high burnups during reactor operation.

ACKNOWLEDGEMENT

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REFERENCES